



mERLin: materials enhanced ERL for increased sustainability

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SuperSurfer meeting

Wuppertal University

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BMBF project plan / funding



- Novel dual target sputtering process for energy-efficient SRF technology (not funded)
- Sustainable operation of electron accelerators (not funded)
- Combined electromagnetic-thermal numerical simulations considering layered surface structures (funded)



Novel dual target sputtering process for energy-efficient SRF technology

- Coating of RF samples for the Quadrupole Resonator (QPR)
- Realization of novel in-cavity dual target sputtering process
- Inner coating of copper cavities
- Performance tests on QPR samples and cavities
- Coating of structures for the consortium partners (HOM antennae, QPR cups, samples)

Possible superconducting materials for RF cavities



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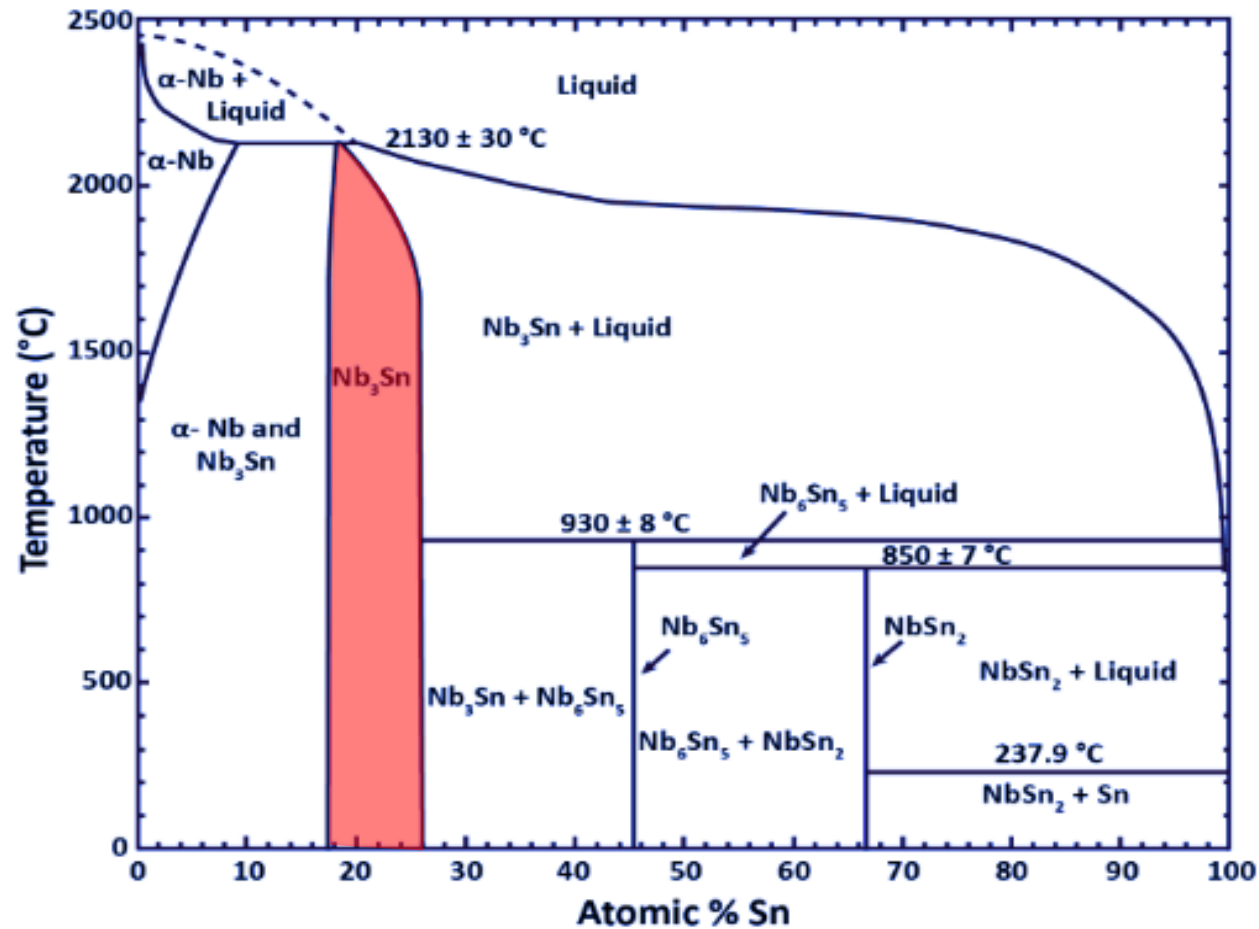
Material	Critical Temp. T_c [K]	Normal-state resistivity ρ_n [$\mu\Omega\text{cm}$]	Critical Field $H_c(0)$ [T]	Lower Critical field $H_{c1}(0)$ [T]	Upper Critical field $H_{c2}(0)$ [T]	Penetration depth $\lambda(0)$ [nm]	Δ [meV]	Type
Nb	9.23	2	0.2	0.18	0.28	40	1.5	II
Pb	7.2		0.08	N/A	N/A	48		I
NbN	16.2	70	0.23	0.02	15	200-350	2.6	II, B1 comp.
NbTiN	17.3	35		0.03		150-200		II, B1 comp.
Nb₃Sn	18	20	0.54	0.05	30	80-100	3.1	II, A15
V ₃ Si	17				24.5	179		II, A15
Mo ₃ Re	15		0.43	0.03	3.5	140		II, A15
MgB ₂	40	0.1-10	0.43	0.03	3.5-60	140	2.3/7.2	II- 2 gaps
YBCO	93		1.4	0.01	100	150	20	d-wave
Pnictides	30-55		0.5-0.9	30	>100	200	10-20	

Whistler 2015, SRF Tutorial - Pushing Nb Performance - A.-M. Valente-Feliciano

Nb-Sn phase diagram

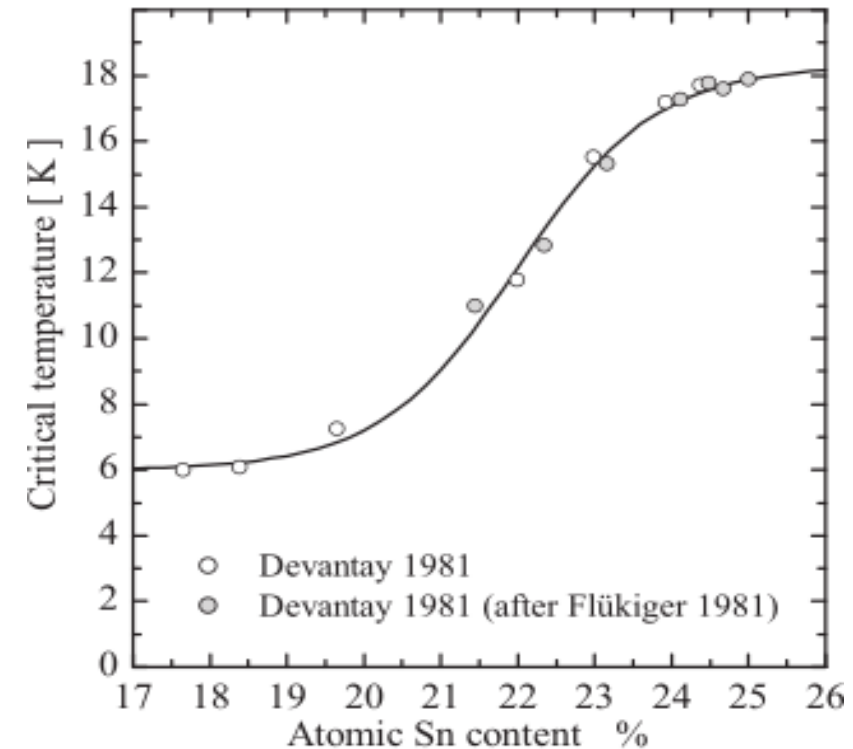
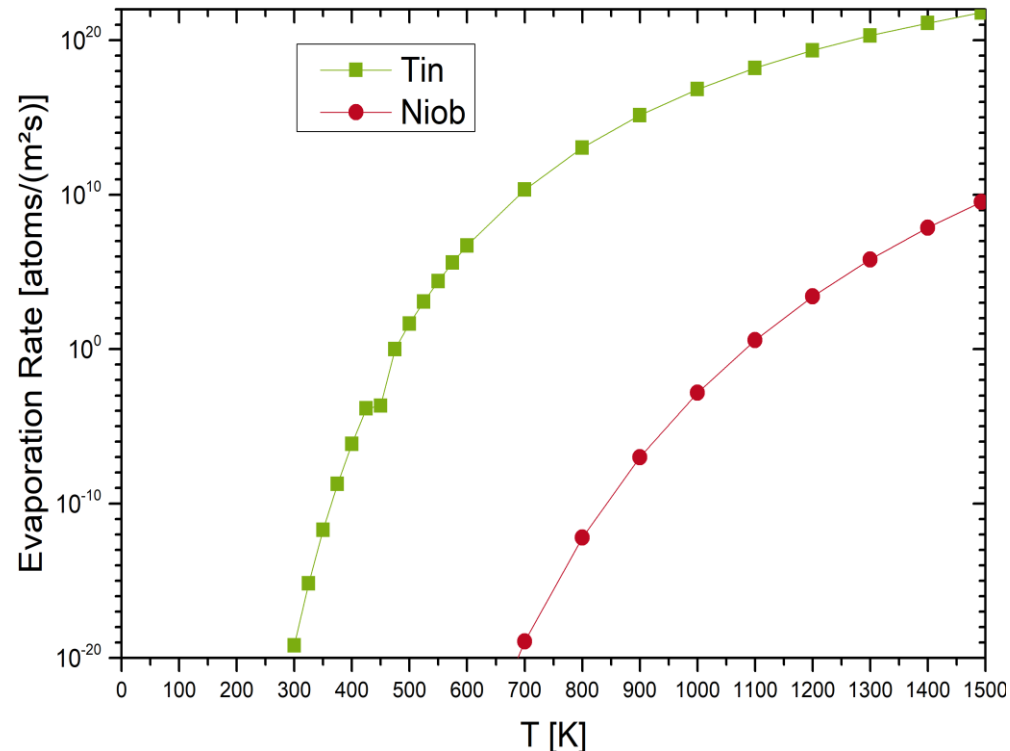


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Charlesworth JP, Macphail I, Madsen PE., Journal of Materials Science. 1970 Jul 1;5(7):580-603.

Challenge: Vapor-pressure of Sn

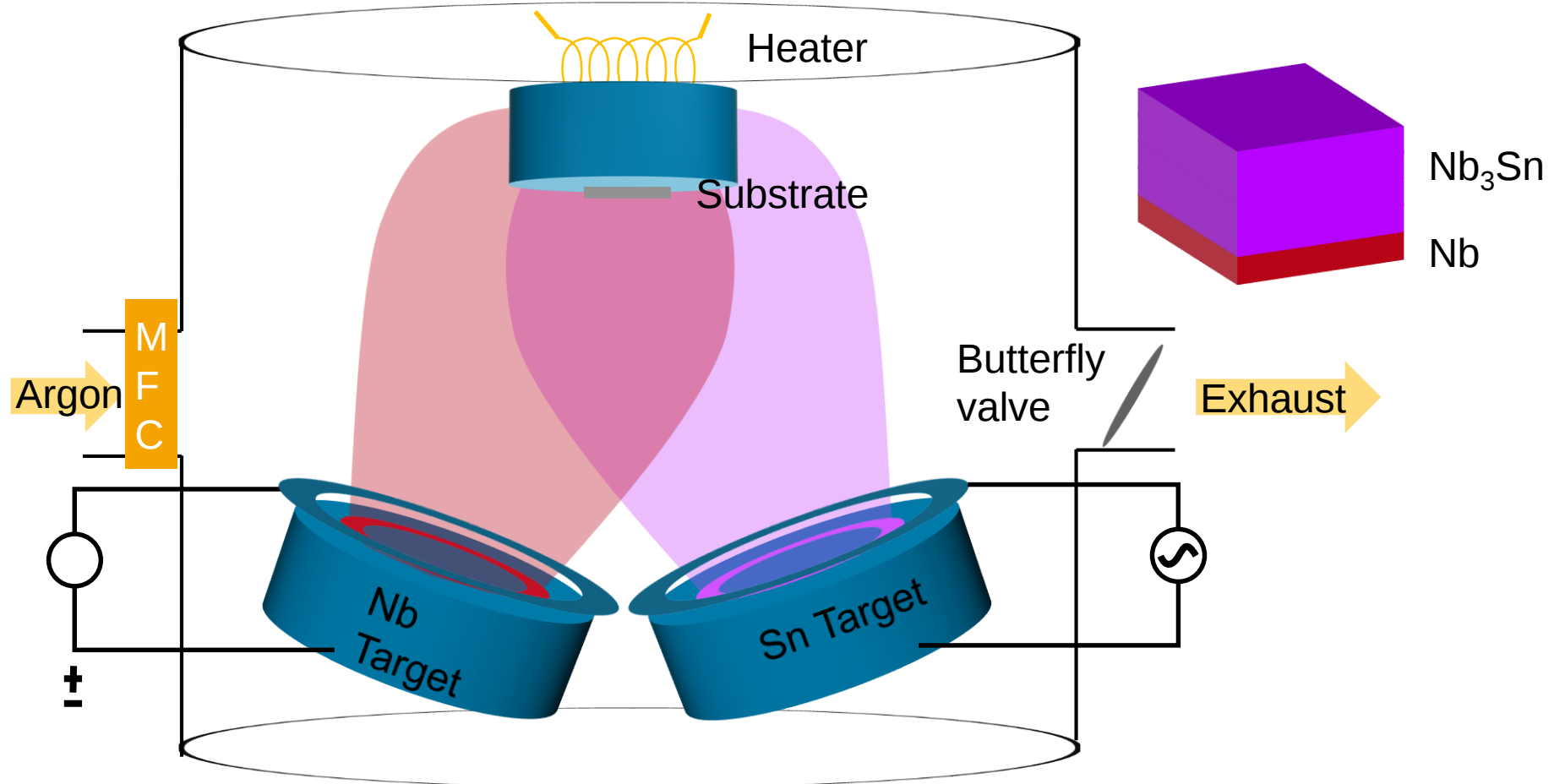


Literature results for the critical temperature as functions of Nb–Sn composition.

TU Darmstadt approach: Nb_3Sn co-sputtering



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Nils Schäfer

Nb₃Sn cavity roadmap



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1. Optimization of the sputtering parameters (sputter power, substrate temperature, etc.) on fused silica substrate
2. Adaptation of the growth parameters (further optimization of growth temperature etc.) for copper substrate
3. Upscaling of the sputtering process to the cavity geometry:
 - a. Optimizing the sputtering parameters for the new (larger) sputtering chamber
 - b. Design and production of the mini double ring magnetron for cavity sputtering
 - c. Inner coating of Cu cavities

N. Schäfer, N. Karabas, J. P. Palakkal, S. Petzold, M. Major, N. Pietralla, and L. Alff, **Kinetically induced low-temperature synthesis of Nb₃Sn thin films**, J. Appl. Phys. **128**, 133902 (2020)

E. Barzi, B. C. Barish, R. A. Rimmer, A. Valente-Feliciano, C. M. Rey, W.A. Barletta, E. Nanni, M. Nasr, M. Ross, M. Schneider, S. Tantawi, P. B. Welandar, E. I. Simakov, I. O. Usov, L. Alff, N. Karabas, M. Major, J. P. Palakkal, S. Petzold, N. Pietralla, N. Schäfer, A. Kikuchi, H. Hayano, H. Ito, S. Kashiwaji, H. Monjushiro, H. Hama, F. Hona, K. Umemori, K. Takahashi, T. Takahashi, Y. Kondo, K. Yamakawa, K. Kon, T. Kubo, **An Impartial Perspective for Superconducting Nb₃Sn coated Copper RF Cavities for Future Accelerators**, arXiv:2203.09718 [physics.acc-ph] (2022)

N. Schäfer, D. Günzing, T. Jiang, N. Karabas; A. Arzumanov, D. Motta-Meira, K. Ollefs, P. Komissinskiy, M. Major, M. Arnold, N. Pietralla, H. Wende, L. Molina-Luna, D. Lützenkirchen-Hecht, L. Alff, **Role of kinetic energy on Nb₃Sn thin films by low-temperature co-sputtering**, J. Appl. Phys. **134**, 043903 (2023)

Physical properties of Nb₃Sn films grown on Cu – conclusions



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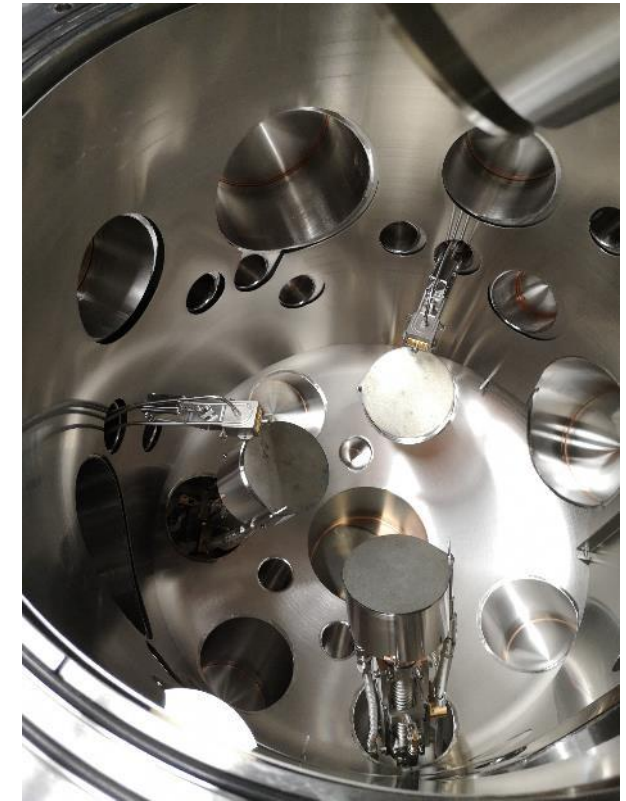
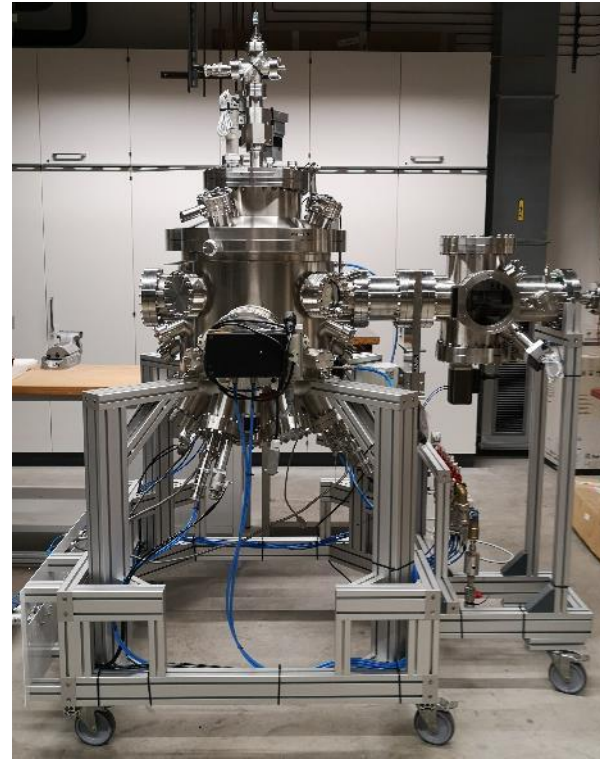
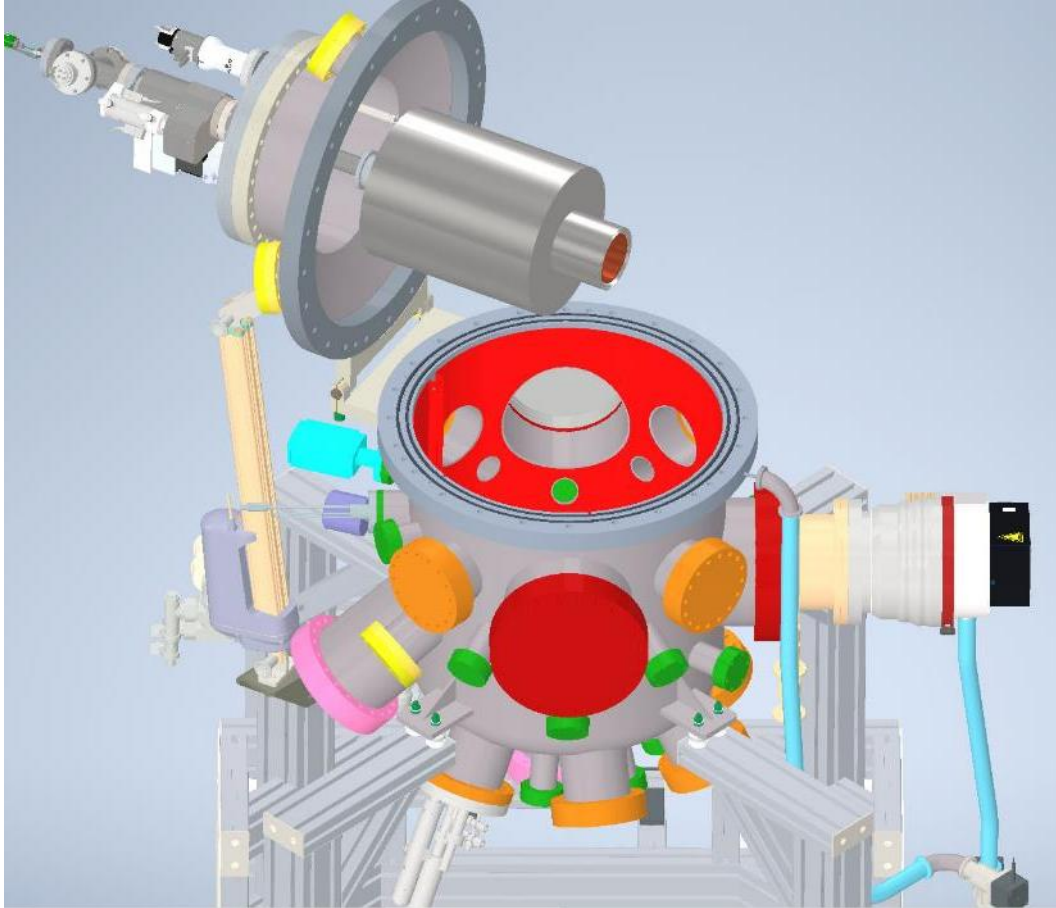
The thin film synthesis results in Nb₃Sn layers with overall highly beneficial properties for their application as coatings in copper based SRF cavities.

At processing temperatures where copper diffusion is negligible, around 480 °C, a critical temperature of 16.8K can be achieved. At the same time, H_{c1} is enhanced which enhances the applicable acceleration gradients. Low surface roughness and high mechanical stability further makes these coatings excellent candidates for cavity applications.

Upscaling to copper cavities



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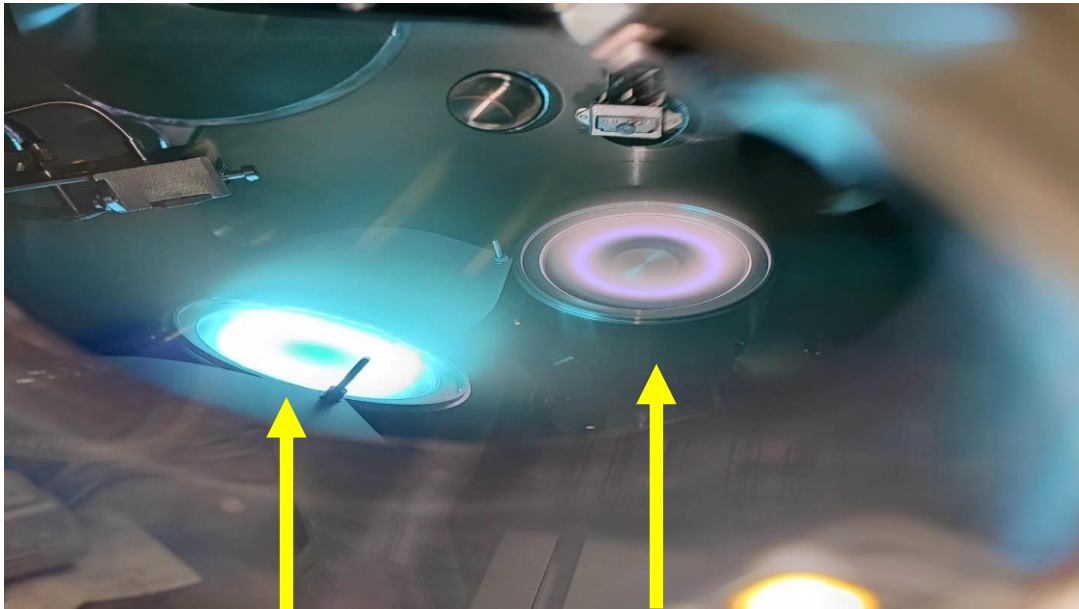


Upscaling to copper cavities



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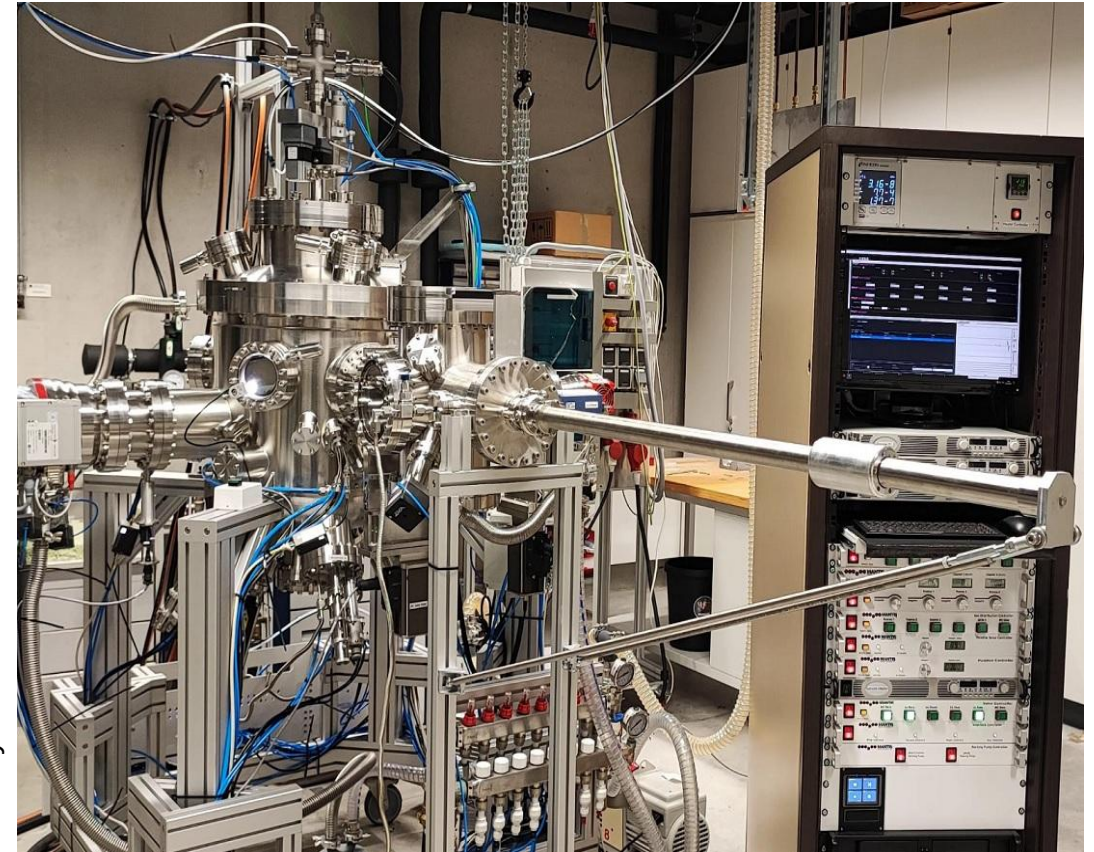
thin film
technology
ATFT



Nb

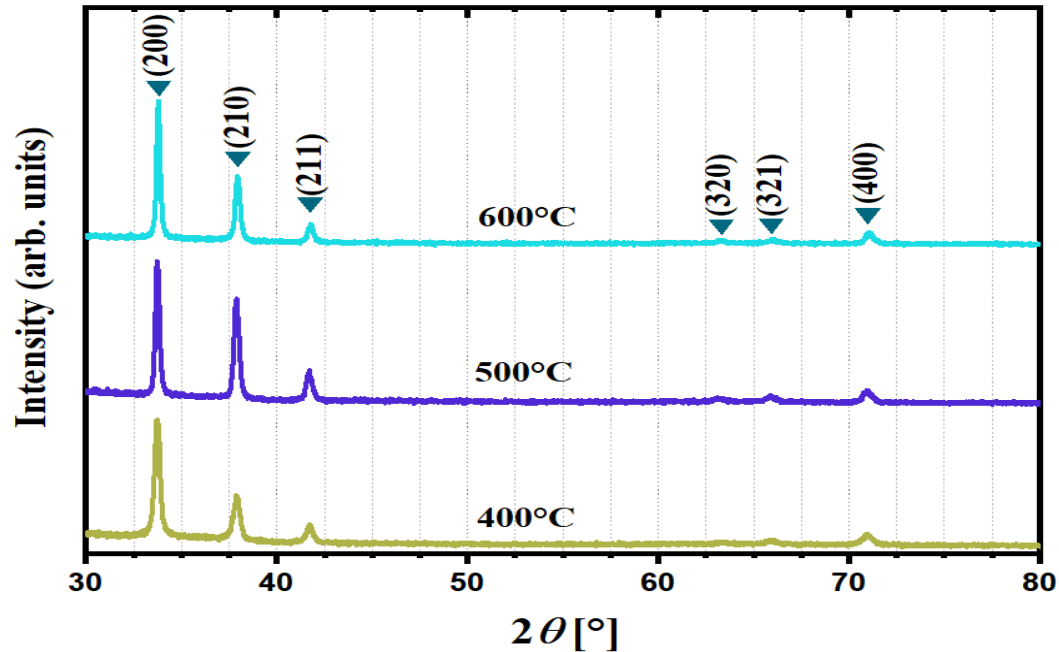
Sn

Alexey Arzumanov

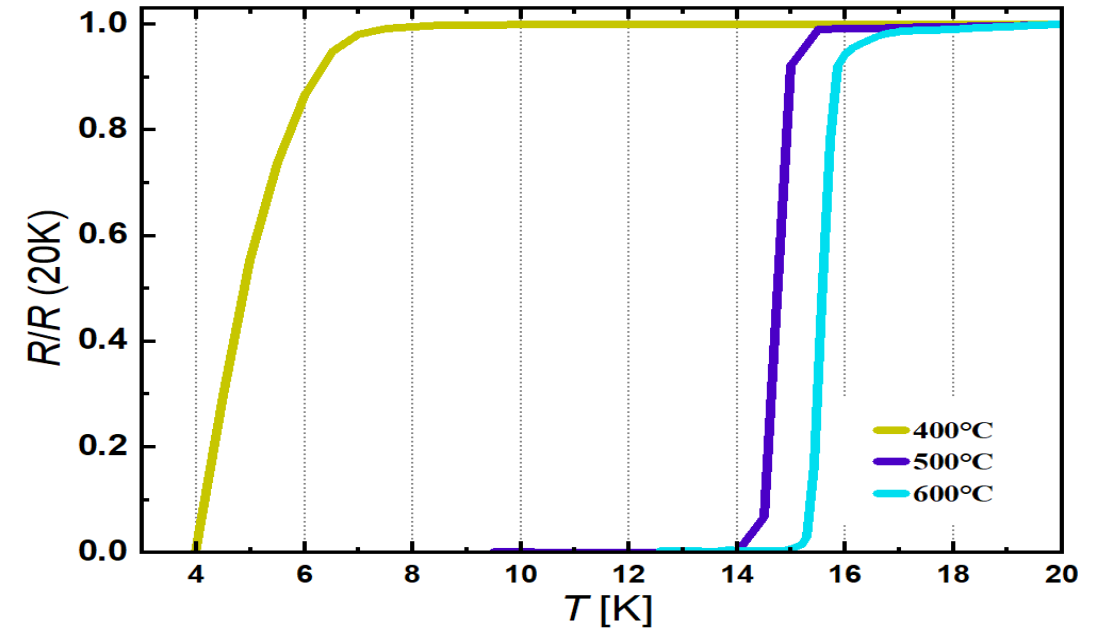


Upscaling to copper cavities

300 nm Nb₃Sn films grown at different substrate temperature on fused silica substrate



X-ray diffraction patterns



Resistivity normalized to the resistivity at 20 K

Sputtering parameters:

DC sputtering

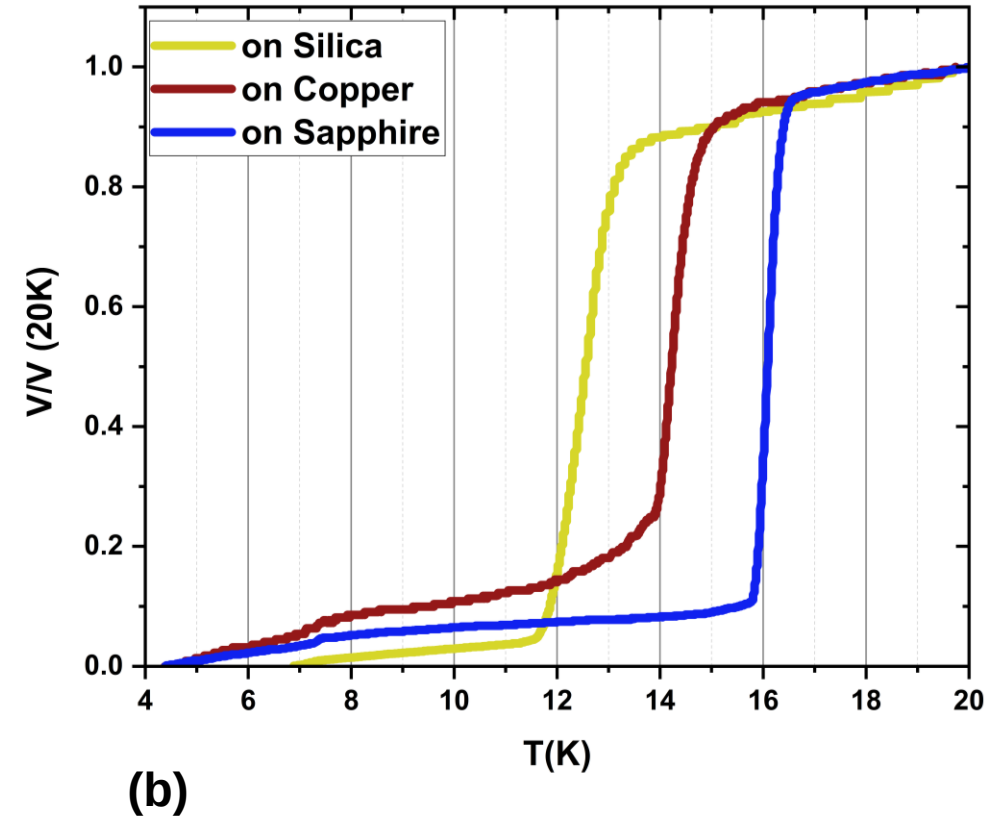
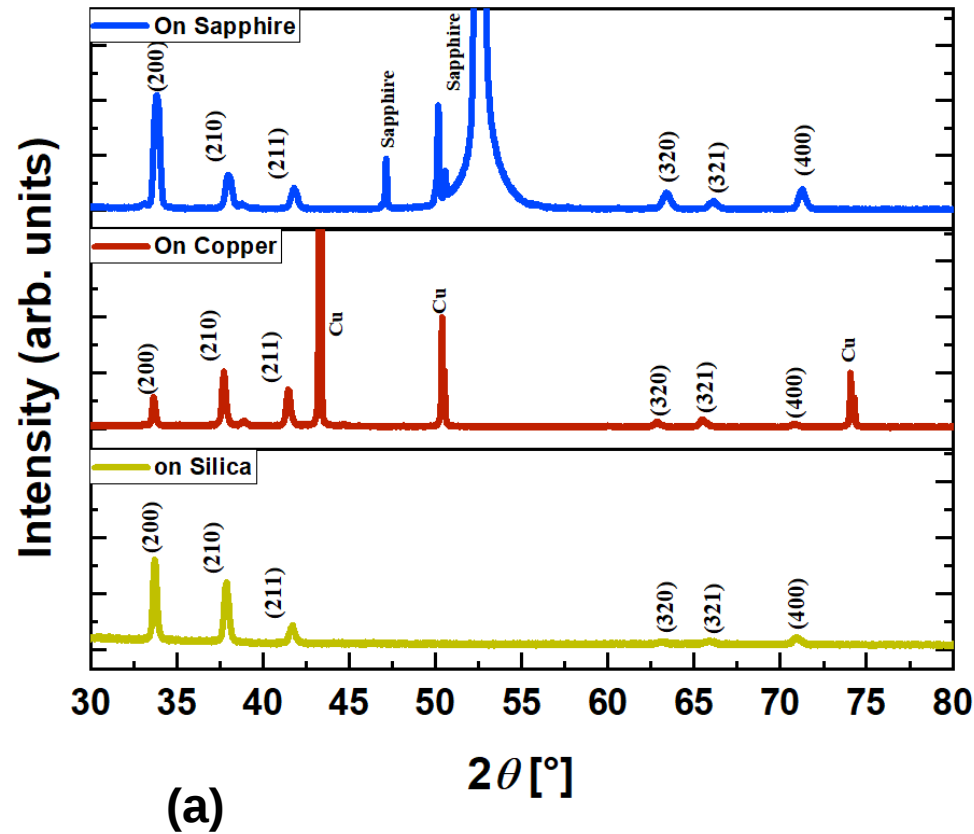
$I_{\text{Nb}} = 450 \text{ mA}$

$I_{\text{Sn}} = 80 \text{ mA}$

Amir Farhood

T_s (°C)	400	500	600
Nb (at%)	74.9±1.6	74.6±0.4	74.0±0.4

Nb₃Sn sputtered on substrates of fused silica, sapphire and copper at 500 °C to investigate the impact of substrate



a) XRD patterns of Nb₃Sn thin films grown on different substrates

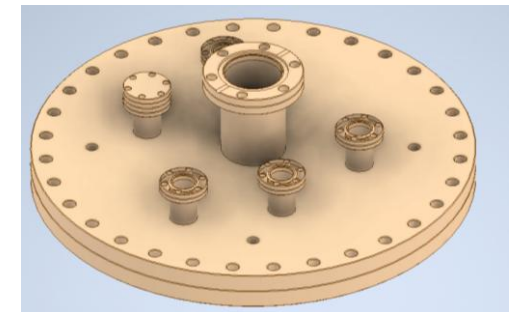
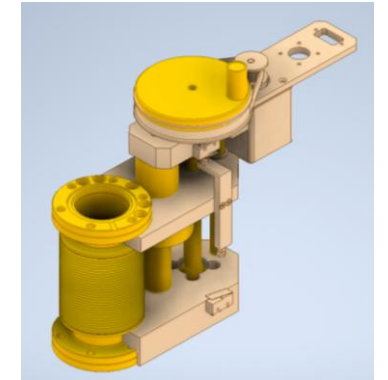
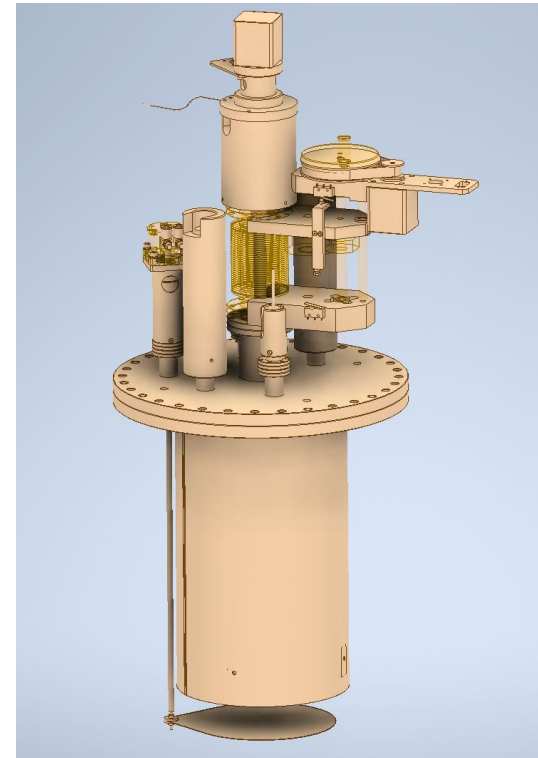
b) Voltage normalized to the voltage at 20 K of thin films measured by coil amplitude method (Meissner effect)

Amir Farhood

- Disc coating (for Hamburg)
- Antenna coating with Nb_3Sn (for Mainz)



New top cover with Z-shift for the antenna coating



Cylindric test shape



**Sputtering condition at the top surface of antenna like shape
(on **silica substrate**)**

Best sputtering condition:

Fused Silica substrate

Pressure: $2 \cdot 10^{-2}$ mbar

I Sn: 80 mA

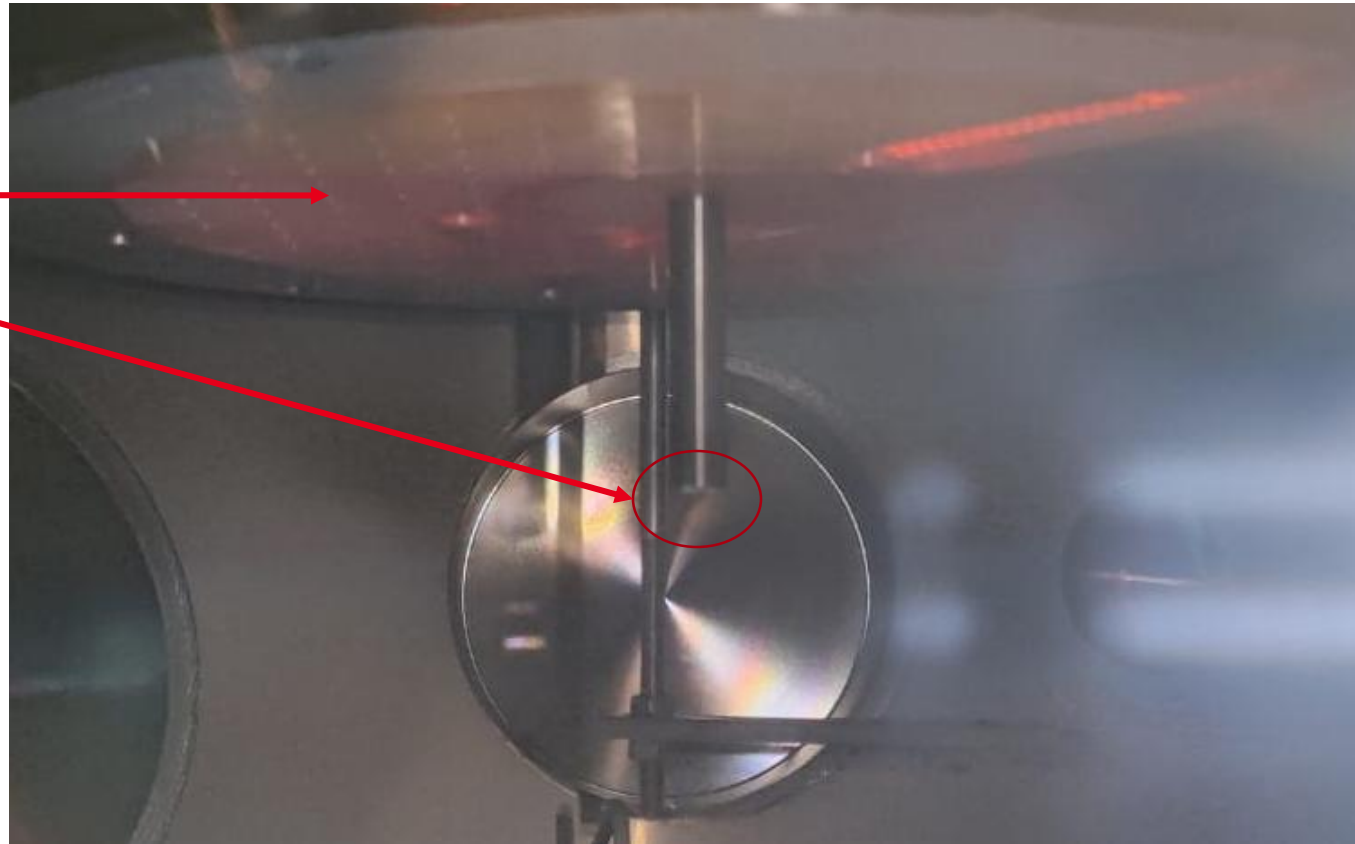
I Nb: 450 mA

$P_{Nb}/P_{Sn} = 4.4$

R speed = 1 rpm

Duration: 2 hour

Approx. thickness ≈ 500 nm



Amir Farhood
Alexey Arzumanov

7. DEPOSITING ON 3D OBJECTS | ON COPPER RF ANTENNA



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ANTENNA COATING

sputtering condition:

Pressure: $2 \cdot 10^{-2}$ mbar

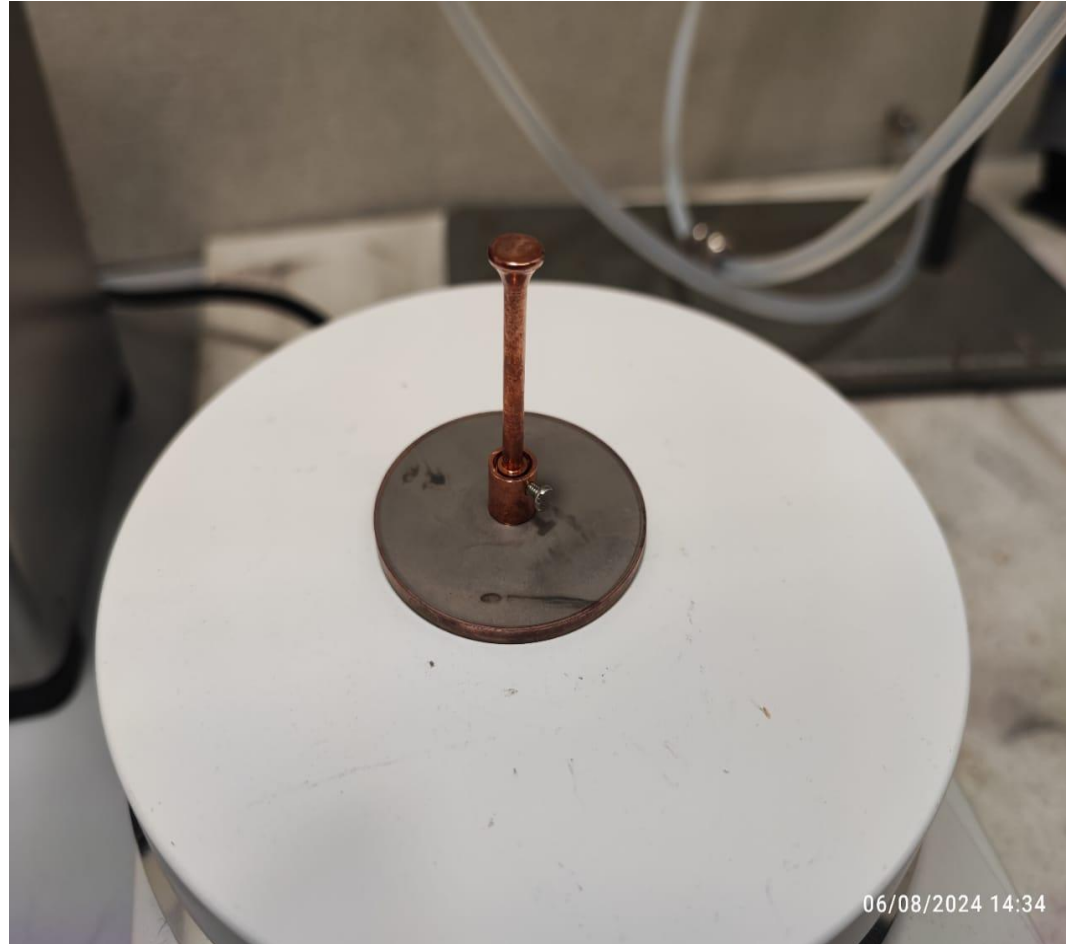
I Sn: 79 mA

I Nb: 450 mA

$P_{Nb}/P_{Sn} = 4.4$

Duration: 2.5 hour

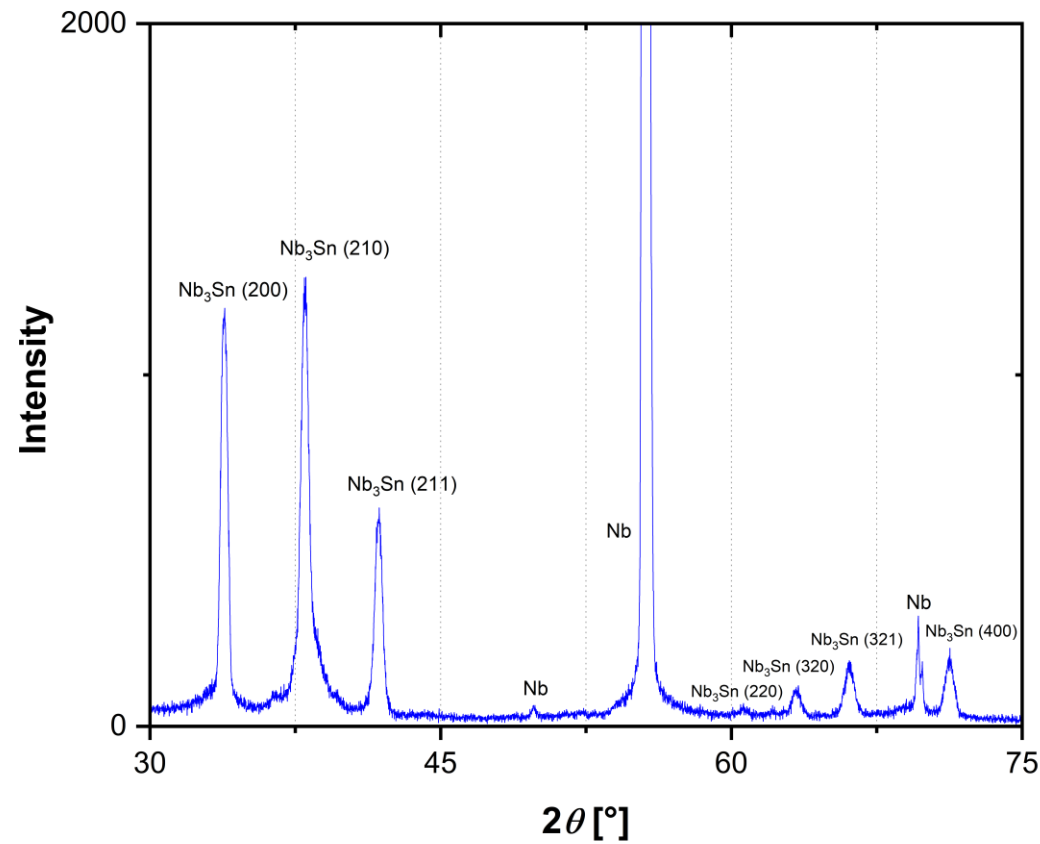
Approx. thickness: 600 nm



Coating of 2 inch Nb disc by Nb_3Sn



Nb disc before coating

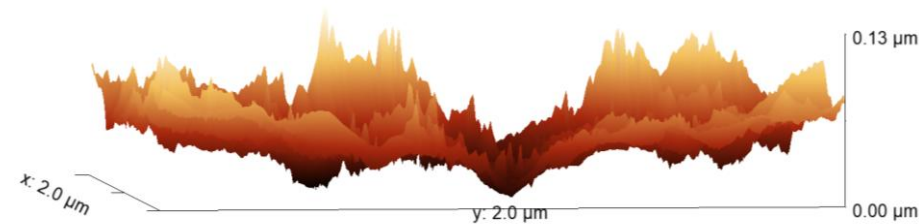
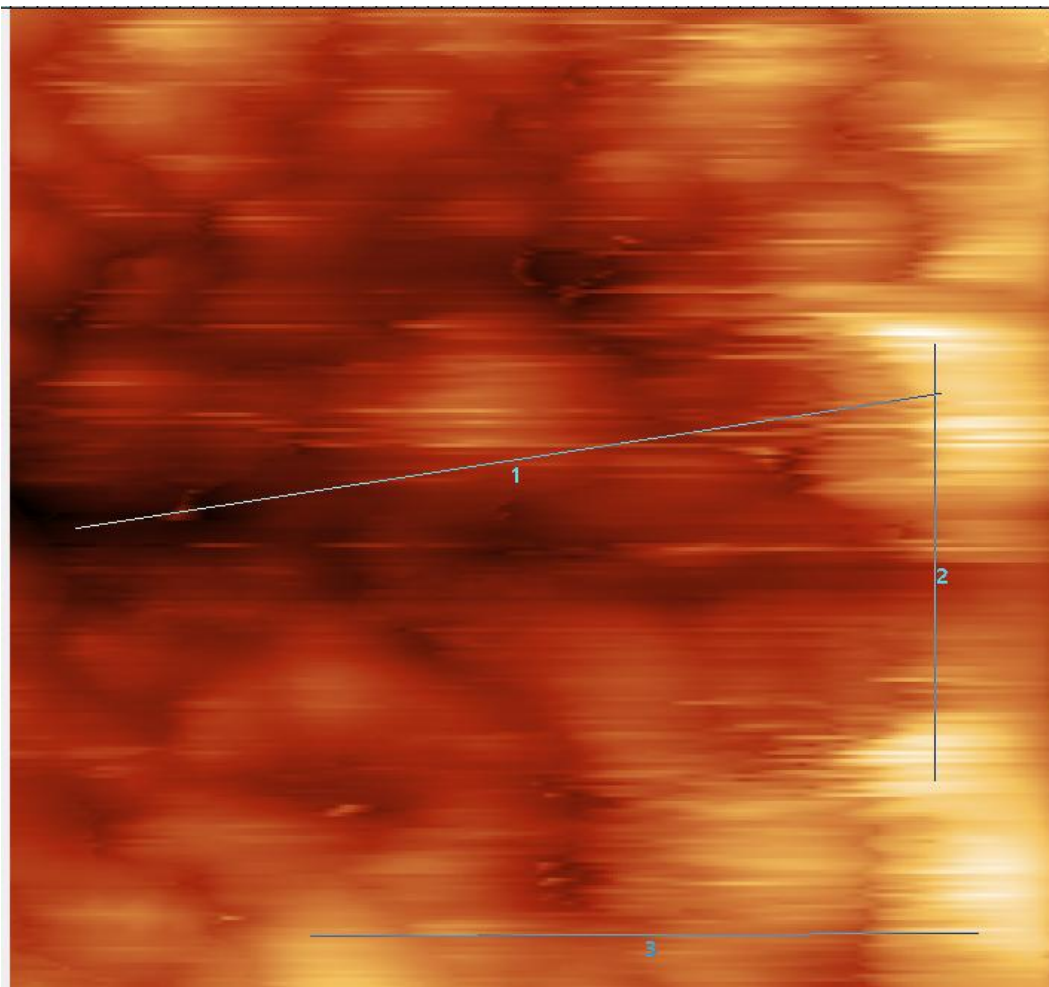


Phase pure Nb_3Sn , with Nb peaks from the substrate

AFM measurements

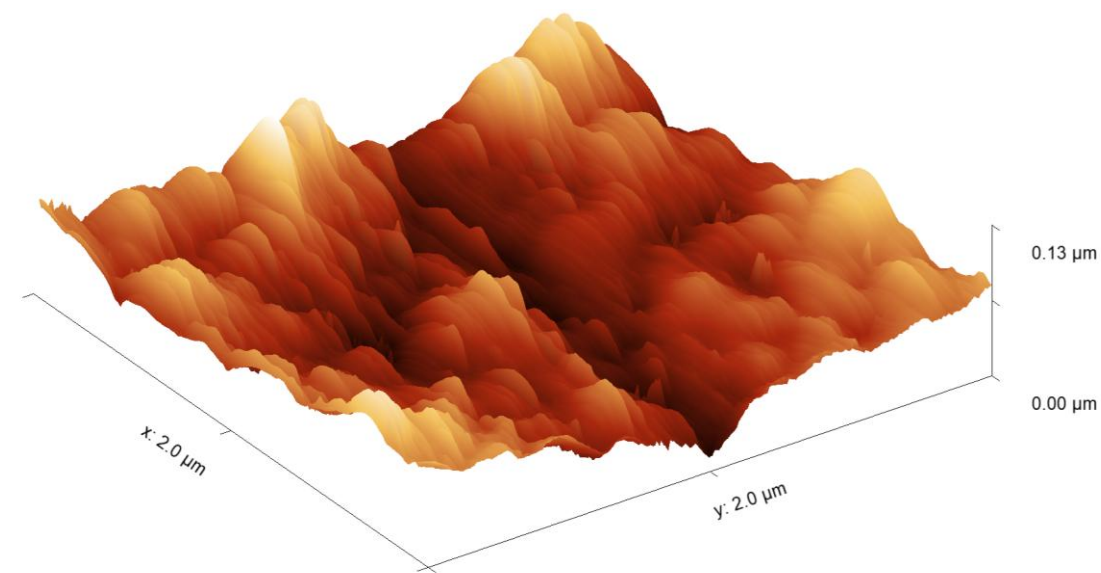
Before Nb₃Sn coating

- 1: 112 nm
- 2: 23 nm
- 3: 29 nm



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thin film
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Area: 2μm * 2μm

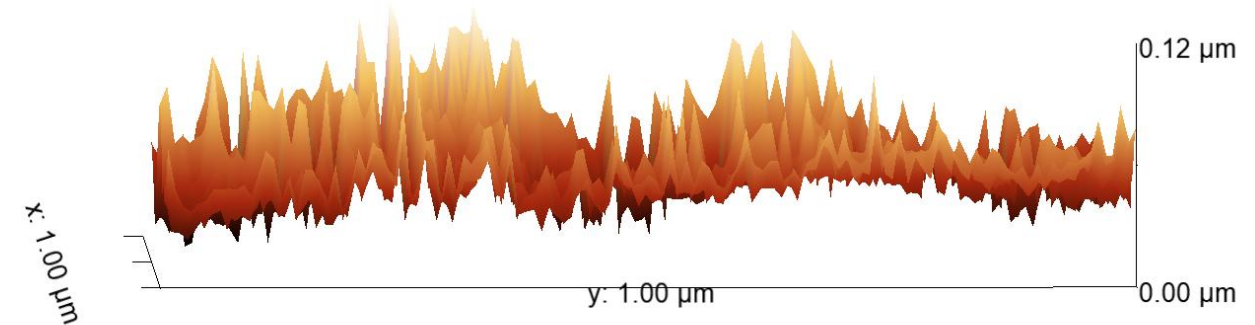
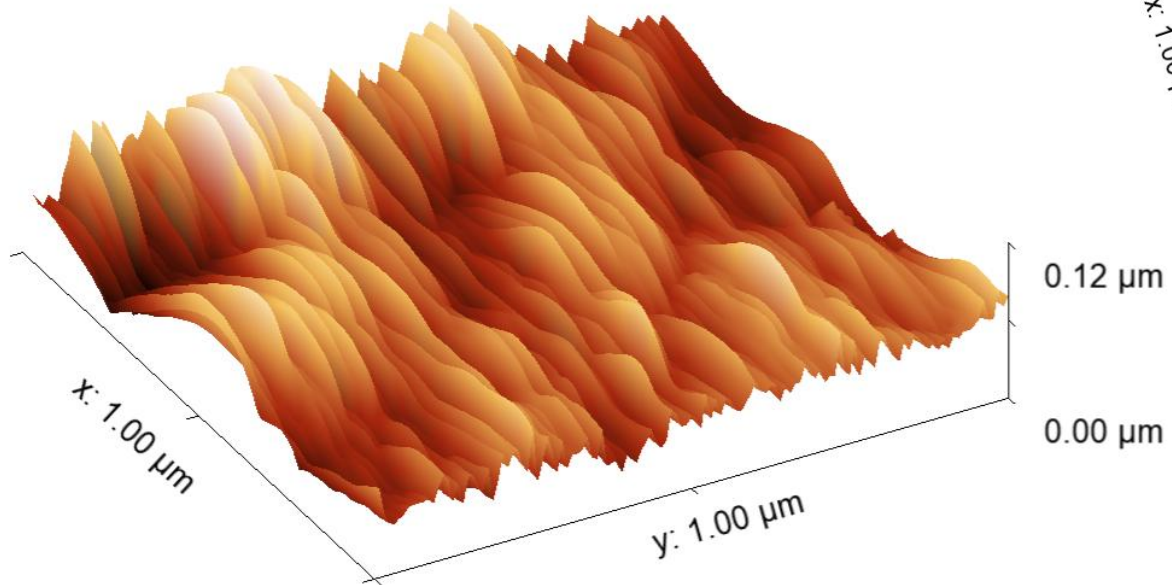
RMS: 39.1 ± 6.6 nm

AFM measurements

Before Nb₃Sn coating



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Area: 1μm * 1μm

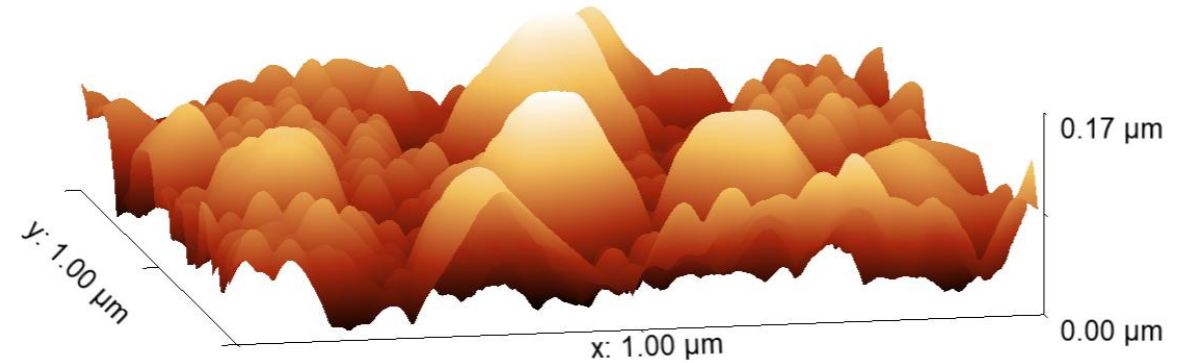
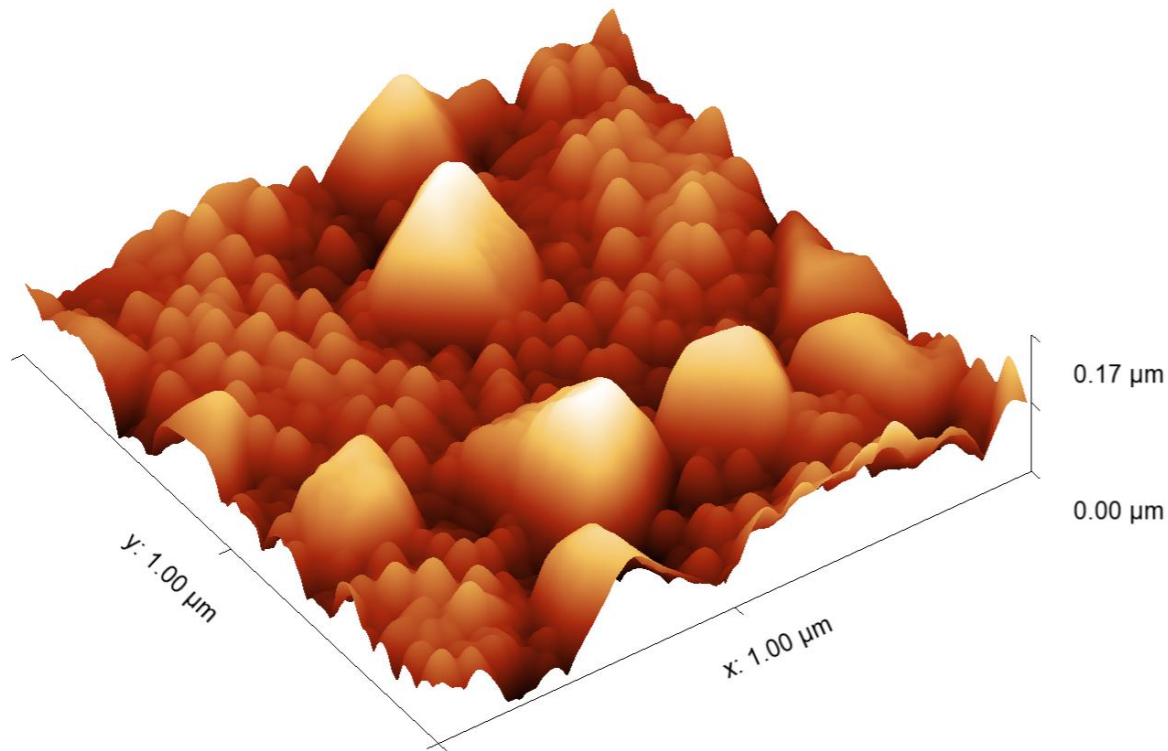
RMS: 31.3 ± 8.1 nm

AFM measurements

After Nb_3Sn coating



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Area: $1\mu\text{m} * 1\mu\text{m}$

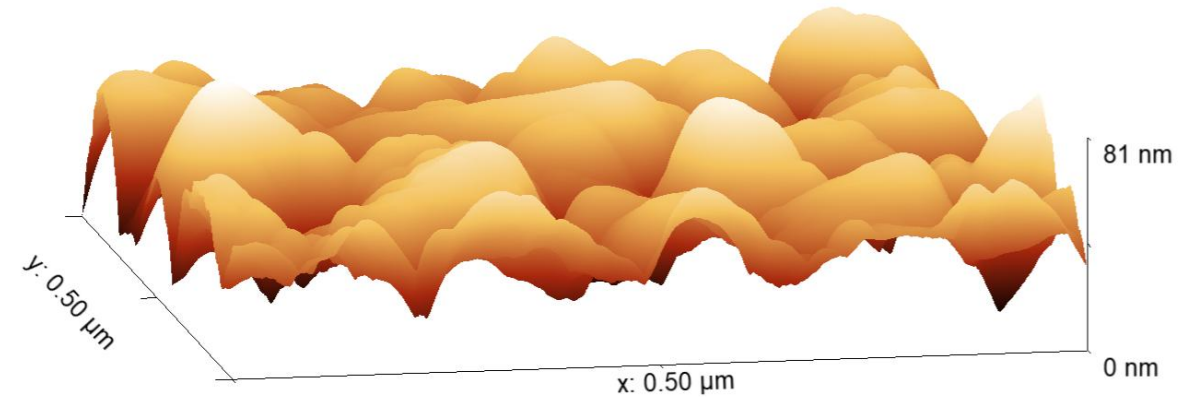
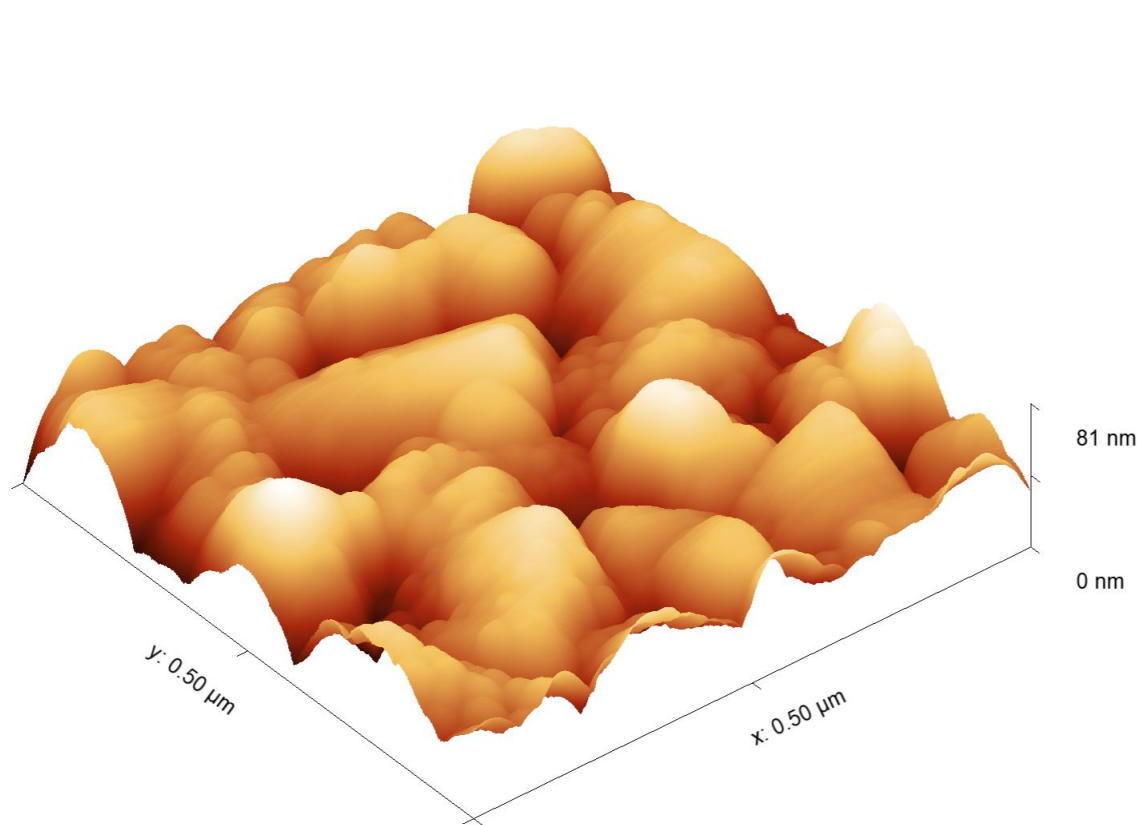
RMS: $18.9 \pm 9.5 \text{ nm}$

AFM measurements

After Nb_3Sn coating



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Area: $0.5 \mu\text{m} * 0.5 \mu\text{m}$

RMS: $11.5 \pm 2.8 \text{ nm}$

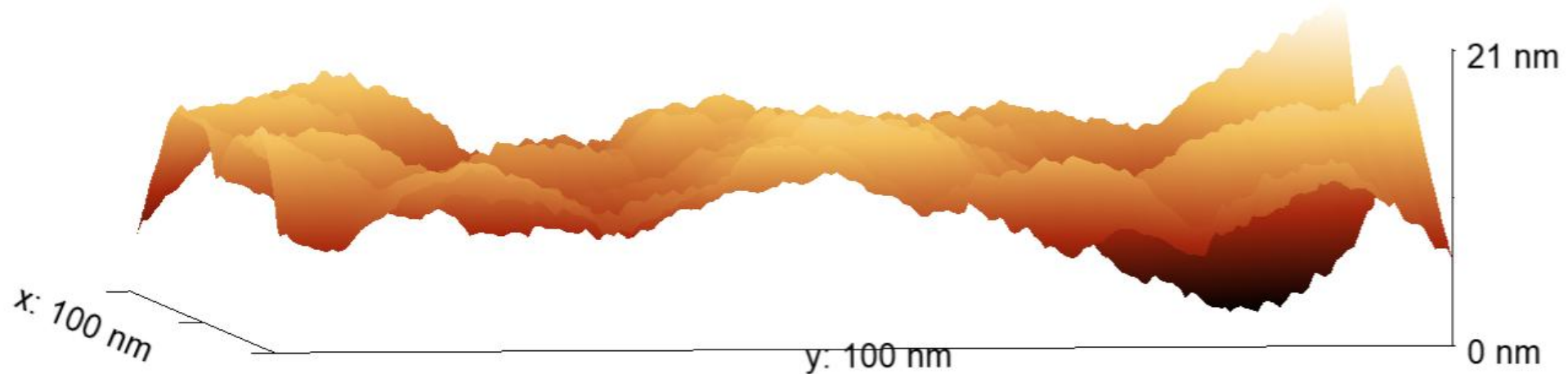
AFM measurements

After Nb₃Sn coating

High resolution measurement: 1Å (lateral resolution)



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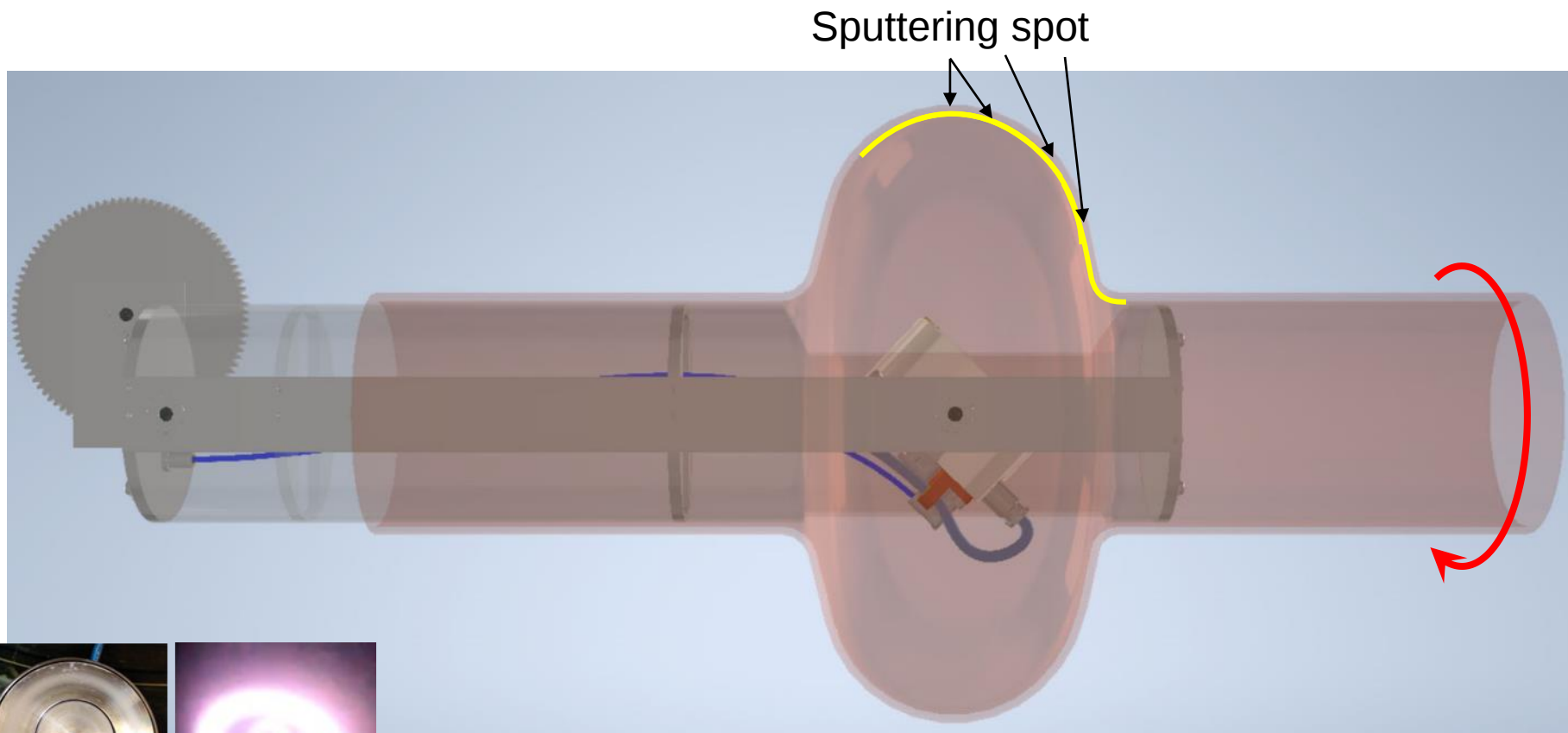
Area: 0.1 μm * 0.1 μm

RMS: 7.7 ± 4.5 nm

Cavity sputtering



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In cooperation with Fraunhofer FEP, Dresden

Acknowledgement

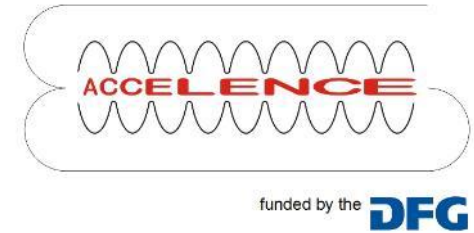


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Norbert Pietralla
Michaela Arnold



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